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Zero Voltage Switch

This series is designed for thyristor control in a variety of AC power switching applications for AC input voltages of 24 V, 120 V, 208/230 V, and 277 V @ 50/60 Hz.

Applications:

- Relay Control
- Valve Control
- Heater Control
- Lamp Control
- On–Off Motor Switching
- Differential Comparator with Self–Contained Power Supply for Industrial Applications
- Synchronous Switching of Flashing Lights



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ZERO VOLTAGE SWITCH

SEMICONDUCTOR TECHNICAL DATA



Figure 1. Representative Block Diagram

AC Input Voltage (50/60 Hz) Vac	Input Series Resistor (R _S) kΩ	Dissipation Rating for R _S w
24	2.0	0.5
120	10	2.0
208/230	20	4.0
277	25	5.0

ORDERING INFORMATION

PLASTIC PACKAGE

CASE 646

Device	Operating Temperature Range	Package
CA3059	$T_A = -40^\circ$ to $+85^\circ$ C	Plastic DIP

FUNCTIONAL BLOCK DESCRIPTION

1. Limiter-Power Supply — Allows operation of the CA3059 directly from an AC line. Suggested dropping resistor (R_S) values are given in the table below.

2. Differential On/Off Sensing Amplifier — Tests for condition of external sensors or input command signals. Proportional control capability or hysteresis may be implemented using this block.

3. Zero-Crossing Detector — Synchronizes the output pulses to the zero voltage point of the AC cycle. This synchronization eliminates RFI when used with resistive loads.

4. **Triac Drive** — Supplies high-current pulses to the external power controlling thyristor.

5. **Protection Circuit** — A built-in circuit may be actuated, if the sensor opens or shorts, to remove the drive current from the external triac.

6. **Inhibit Capability** — Thyristor firing may be inhibited by the action of an internal diode gate at Pin 1.

7. **High Power DC Comparator Operation** — Operation in this mode is accomplished by connecting Pin 7 to Pin 12 (thus overriding the action of the zero-crossing detector). When Pin 13 is positive with respect to Pin 9, current to the thyristor is continuous.

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
DC Supply Voltage		V _{CC}		Vdc
(Between Pins 2 and 7)			12	
DC Supply Voltage		V _{CC}		Vdc
(Between Pins 2 and 8)			12	
Peak Supply Current (Pins 5 and 7)		I _{5,7}	±[50	mA
Fail-Safe Input Current (Pin 14)		I ₁₄	2.0	mA
Output Pulse Current (Pin 4) (Note 1)		l _{out}	150	mA
Junction Temperature		TJ	150	°C
Operating Temperature Range		T _A	– 40 to + 85	°C
Storage Temperature Range		T _{stg}	– 65 to + 150	°C

ELECTRICAL CHARACTERISTICS (Operation @ 120 Vrms, 50-60 Hz, T_A = 25°C [Note 2])

Characteristic	Figure	Symbol	Min	Тур	Max	Unit
DC Supply Voltage Inhibit Mode R _S = 10 k, I _L = 0	2	Vs	6.1	6.5	7.0	Vdc
$R_{S} = 5.0 \text{ k}, \text{ I}_{L} = 2.0 \text{ mA}$ Pulse Mode			5	6.1	/ –	
R _S = 10 k, I _L = 0 R _S = 5.0 k, R _L = 2.0 mA		- F	6.0	6.4 6.2	7.0	
Gate Trigger Current (V _{GT} = 1.0 V, Pins 3 and 2 connected)	3	IGT		160	—	mA
Peak Output Current, Pulsed With Internal Power Supply, V _{GT} = 0	3	Іом	KO.			mA
Pin 3 Open Pins 3 and 2 Connected	CH P	0, 41	50 90	125 190	_	
With External Power Supply, V _{CC} = 12 V, V _{GT} = 0 Pin 3 Open Pins 3 and 2 Connected		KO.		230 300		
Inhibit Input Ratio (Ratio of Voltage @ Pin 9 to Pin 2)	5	V ₉ /V ₂	0.465	0.485	0.520	
Total Gate Pulse Duration (C _{Ext} = 0) Positive dv/dt	6	tp	70	100	140	μs
Negative dv/dt		τ _n	70	100	140	
Pulse Duration After Zero Crossing ($C_{Ext} = 0, R_{Ext} = \infty$)	6					μs
Positive dv/dt Negative dv/dt		t _{p1} t _{n1}		50 60	_	
Output Leakage Current Inhibit Mode (Note 3)	3	I ₄		0.001	10	μA
nput Bias Current	7	I _{IB}		0.15	1.0	μA
Common Mode Input Voltage Range (Pins 9 and 13 Connected)	_	V _{CMR}		1.4 to 5.0	—	Vdc
Inhibit Input Voltage	8	V ₁		1.4	1.6	Vdc
External Trigger Voltage		V ₆ -V ₄		1.4	_	Vdc

NOTES: 1. Care must be taken, especially when using an external power supply, that total package dissipation is not exceeded.

2. The values given in the Electrical Characteristics Table at 120 V also apply for operation at input voltages of 24 V, 208/230 V, and 277 V, except for Pulse Duration test. However, the series resistor (R_S) must have the indicated value, shown in Table A for the specified input voltage. 3. I₄ out of Pin 4, 2.0 V on Pin 1, S₁ position 2.

TEST CIRCUITS

(All resistor values are in ohms)



with Associated Waveform

TYPICAL CHARACTERISTICS





Figure 14. Circuit Schematic

APPLICATION INFORMATION

Power Supply

The CA3059 is a self-powered circuit, powered from the AC line through an appropriate dropping resistor (see Table A). The internal supply is designed to power the auxiliary power circuits.

In applications where more output current from the internal supply is required, an external power supply of higher voltage should be used. To use an external power supply, connect Pin 5 and Pin 7 together and apply the synchronizing voltage to Pin 12 and the DC supply voltage to Pin 2 as shown in Figure 4.

Operation of Protection Circuit

The protection circuit, when connected, will remove current drive from the triac if an open or shorted sensor is detected. This circuit is activated by connecting Pin 13 to Pin 14 (see Figure 1).

The following conditions should be observed when the protection circuit is utilized:

a. The internal supply should be used and the external load current must be limited to 2 mA with a 5 k Ω dropping resistor.

- b. Sensor Resistance (R_X) and R_P values should be between 2 k Ω and 100 k Ω .
- c. The relationship $0.33 < R_X/R_P < 3$ must be met over the anticipated temperature range to prevent undesired activation of the circuit. A shunt or series resistor may have to be added.

External Inhibit Function

A priority inhibit command applied to Pin 1 will remove current drive from the thyristor. A command of at least +1.2 V @ 10 μ A is required. A DTL or TTL logic 1 applied to Pin 1 will activate the inhibit function.

DC Gate Current Mode

When comparator operation is desired or inductive loads are being switched, Pins 7 and 12 should be connected. This connection disables the zero-crossing detector to permit the flow of gate current from the differential sensing amplifier on demand. Care should be exercised to avoid possible overloading of the internal power supply when operating the device in this mode. A resistor should be inserted between Pin 4 and the thyristor gate in order to limit the current.

PACKAGE DIMENSIONS

PLASTIC PACKAGE CASE 646–06 ISSUE M



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